



可控硅光耦
Photo Triac

ATM30VX

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

[www . aote se mi . co m](http://www.aotese mi .co m)

概述 Description

- ATM303X、ATM304X、ATM306X、ATM308X 系列器件是由一个 GaAs 红外发光二极管和一个单晶硅芯片的过零相位光电双向晶闸管组成的光电耦合器。

The ATM303X, ATM304X, ATM306X and ATM308X series devices are optical couplers composed of GaAs infrared light emitting diodes and zero-crossing phase photoelectric bidirectional thyristor of single crystal silicon chip.

特性 Features

- 峰值击穿电压
Peak breakdown voltage
250V : ATM303X ;
400V : ATM304X ;
600V : ATM306X ;
800V : ATM308X ;
- 输入-输出隔离电压 ($V_{ISO}=3750\text{ Vrms}$)
High isolation voltage between input and output($V_{ISO}=3750\text{ Vrms}$)
- 工作温度 : $-55^{\circ}\text{C} \sim 110^{\circ}\text{C}$
Operating Temperature: $-55^{\circ}\text{C} \sim 110^{\circ}\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准 : UL 1577 , VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022
Safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022

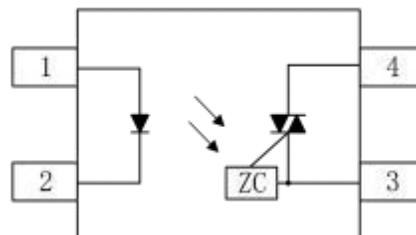
应用 Applications

- 开关电源 , 智能电表
Switching power supply, intelligent meter
- 工业控制 , 测量仪器
Industrial control, measuring instruments
- 办公设备 , 比如复印机
Office equipment such as copiers
- 家用电器 , 比如空调、风扇、热水器等
Household appliances: such as air conditioners, fans, water heaters, etc.

封装和原理图 packageandschematic Diagram



SOP4



Pin Configuration

- Anode
- Cathode
- GND
- VCC



产品型号命名规则 Order code

AT M30VX-UN Y - W(V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特 Aote)
- ② 产品系列 Product Series (M30VT: M303X, M304X, M306X, M308X)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (S: SOP)
- ⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range need to be filled in or left blank)
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中的 “V” 代表 V_{DRM}分档：3、4、6、8
“V” denotes the V_{DRM} digissr：3、4、6、8
- 印字中的 “X” 代表 IFTdigissr：0、1、2、3
“X” denotes the IFT：0、1、2、3
- 印字中 “Y” 代表年份；A(2018),B(2019),C(2020)
“Y” denotes YEAR：A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes Week' s number.
- 印字中 “E” 代表内部代码
“E” denotes Internal code
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free.



绝缘和安规信息 Insulation and safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	>5.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	>5.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	>0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	600	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	5000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	V_{iso}	>3750	V_{rms}	For 1 min

极限参数 Absolute Maximum Ratings ($T_a = 25^\circ C$)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit	
发射端 Input	正向电流 Forward Current	I_F	60	mA	
	反向电压 Backward Voltage	V_R	6	V	
	功耗 Power Dissipation	P_b	100	mW	
	额定值降低因子(在 $T_a = 85^\circ C$ 以上) Power dissipation Derating factor (above $T_a = 85^\circ C$)	P_{DD}	3.8	mW/ $^\circ C$	
接收端 output	断态输出端电压 Off-state output terminal voltage	V_{DRM}	ATM303X	250	V
			ATM304X	400	
			ATM306X	600	
			ATM308X	800	
	峰值重复浪涌电流($p_w = 100\mu s, 120 pps$) Peak repetitive surge current ($p_w = 100\mu s, 120 pps$)	I_{TSM}	1	A	
	开启态电流 (均方根值) On-state current (root mean square value)	$I_{T(RMS)}$	100	mA	
	功耗 Power Dissipation	P_c	300	mW	
额定值降低因子(在 $T_a = 90^\circ C$ 以上) Power dissipation Derating factor (above $T_a = 90^\circ C$)	7.6		mW/ $^\circ C$		
总功耗 Total Power Dissipation	P_{tot}	330	mW		
隔离电压 Isolation Voltage	V_{iso}	3750	V		

参数 Parameter	符号 Symbol	额定值 Rating	单位 Unit
工作温度 Operating Temperature	T_{opr}	-55—110	°C
存储温度 Storage Temperature	T_{stg}	-55—125	°C
焊接温度 Soldering Temperature	T_{sol}	260	°C

*在相对湿度 40% ~ 60%下的进行交流电测试，此时 1、2 脚短接，3、4 脚短接。

* Conduct ACtest at 40% ~60% relative humidity. At this time, pins 1 and 2 are short-circuited, and pins 3 and 4 are short-circuited.

产品特性参数 Electro-optical characteristics (Ta=25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit	
发射端 Input	正向电压 Forward Voltage	V_F	$I_F = 20\text{mA}$	-	1.23	1.5	V	
	反向电流 Back current	I_R	$V_R = 6\text{V}$	-	-	10	μA	
接收端 Output	断态峰值电流 Off-state peak current	ATM303X	$V_{\text{DRM}} = \text{Rated } V_{\text{DRM}}$ $I_F = 0\text{mA}$	-	-	100	nA	
		ATM304X						
		ATM306X						
		ATM308X						
	通态峰值电压 On-state peak voltage		V_{TM}	$I_{\text{TM}} = 100\text{mA peak}$ $I_F = \text{Rated } I_{\text{FT}}$	-	-	3	V
	断态电压临界上升 率 Critical rise rate of off-state voltage	ATM303X	dv/dt	$V_{\text{PEAK}} = \text{Rated } V_{\text{DRM}}$, $I_F = 0$	1000	-	-	V/ μs
ATM304X								
ATM306X								
ATM308X								
抑制电压 (MT1-MT2 高于多少电压不会触发) Suppression voltage (MT1-MT2 will not be triggered if it is higher than this voltage)		V_{inh}	$I_F = \text{Rated } I_{\text{FT}}$	-	-	20	V	
抑制状态的漏电流 Leakage current in suppression state		I_{DRM2}	$I_F = \text{Rated } I_{\text{FT}}$, $V_{\text{DRM}} = \text{Rated } V_{\text{DRM}}$, Off state	-	-	500	μA	
传输特性 Transfer Characteristics	LED 触发电流 LED trigger current	ATM3031	I_{FT}	主端电压 Main terminal Voltage =3V	-	-	15	
		ATM3041						
		ATM3061						
		ATM3081						
		ATM3032						
		ATM3042						
		ATM3062						
		ATM3082						
		ATM3033						
		ATM3043						
	ATM3063							
ATM3083								
维持电流 Maintain current		I_H	-	-	280	-	μA	

典型光电特性曲线 Typical Electro-optical characteristics curves

Fig.1 LED forward current vs Forward voltage

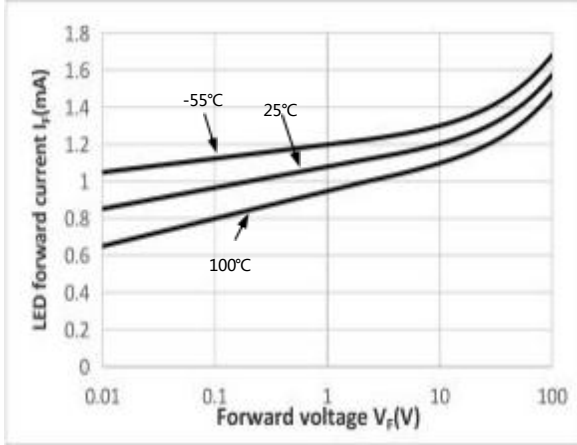


Fig.2 On-state characteristic diagram

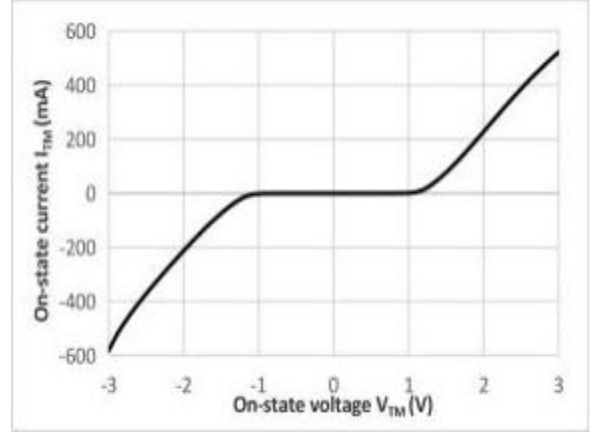


Fig.3 Trigger current vs Ambient temperature

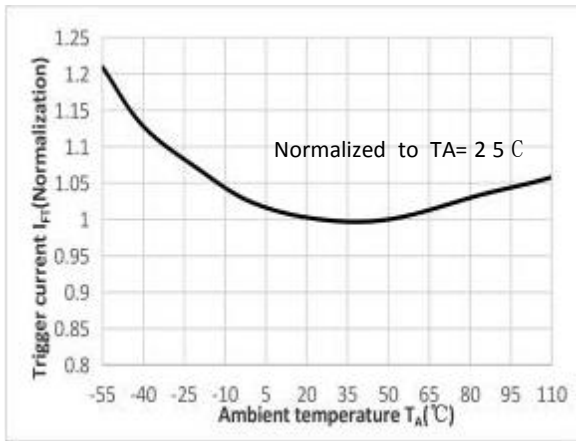


Fig.4 Trigger current vs LED pulse width

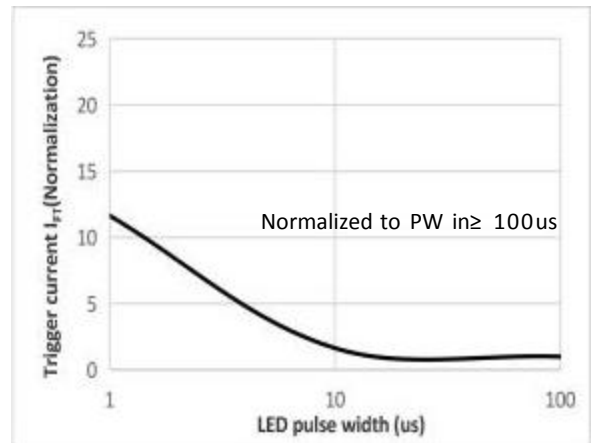


Fig.5 Maintenance current vs Ambient temperature

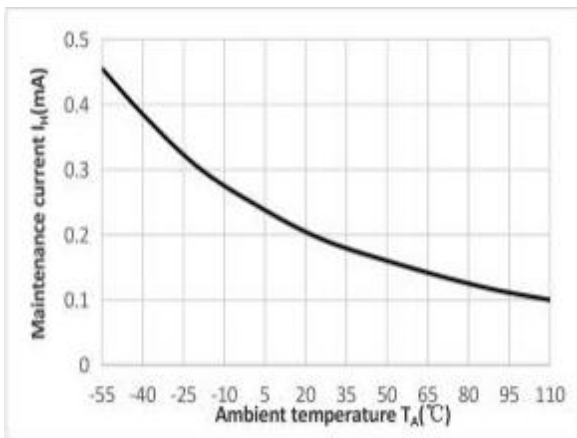


Fig.6 Leakage current vs Ambient temperature

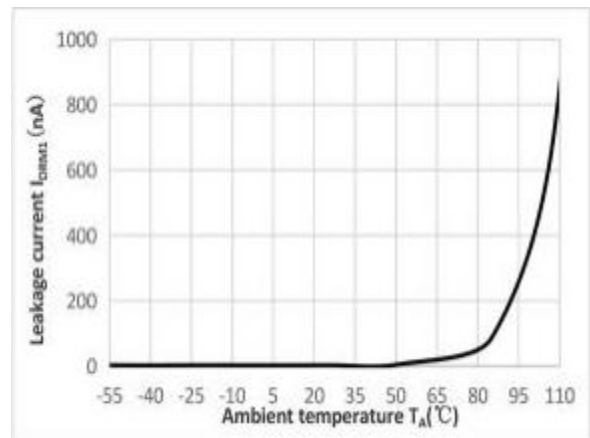


Fig.7 Suppressed state leakage current vs Ambient temperature

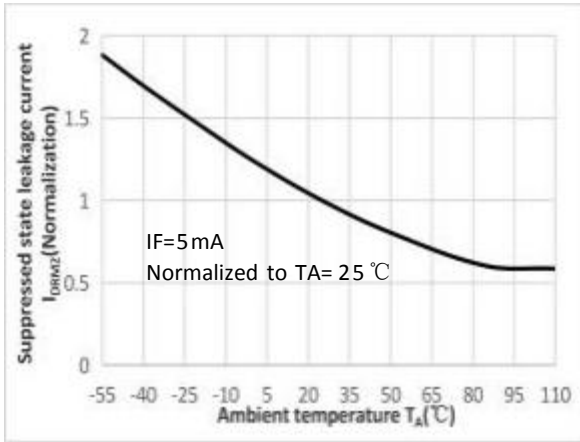


Fig.8 Suppression voltage vs Ambient temperature

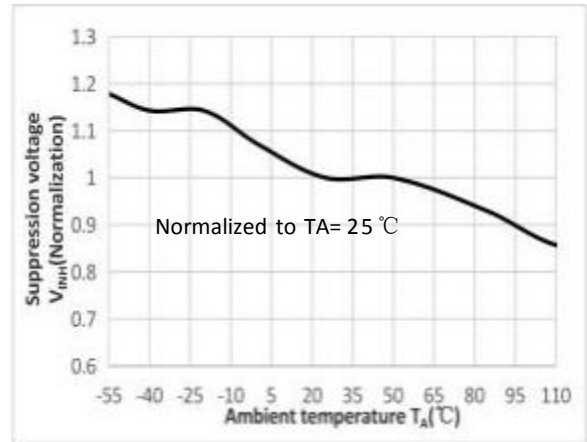
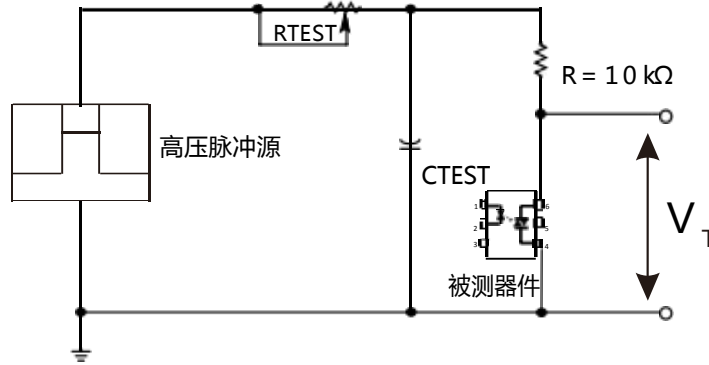
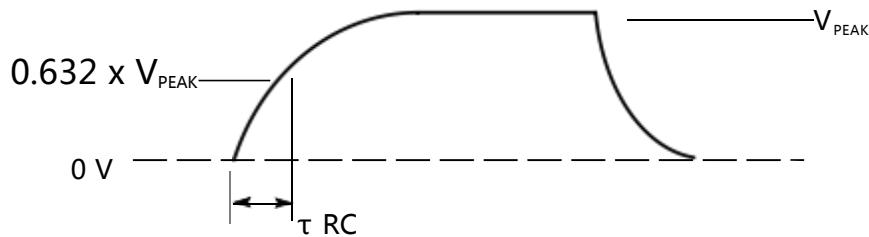


Fig.9 静态 dv/dt 测试电路和波形 Static dv/dt test circuit and waveform



监测 V_T 波形



通过 RC 电路施加于被测器件的输出端的高电压脉冲设置到所需的 V_{PEAK} 值上。LED 电流无需加上。波形 V_T 使用 X100 探头监测。通过调节 R_{TEST} 值， dv/dt (斜度) 增加，直到被测器件观察到被触发 (波形崩溃)。 dv/dt 然后下降，直到被测器件停止被触发。此时，记录 τ_{RC} 值并可计算 dv/dt 了。

The high voltage pulse applied to the output end of the device under test through the RC circuit is set to the desired V_{PEAK} value. LED current does not need to be added. Waveform V_T is monitored with X100 probe. By adjusting the R_{TEST} value, dv/dt (slope) increases until the device under test is observed to be triggered (waveform collapse). Dv/dt then drops until the device under test stops being triggered. At this time, dv/dt can be calculated by recording the value of τ_{RC} .

$$dv/dt = \frac{0.632 \times 400}{\tau_{RC}} = \frac{252}{\tau_{RC}}$$

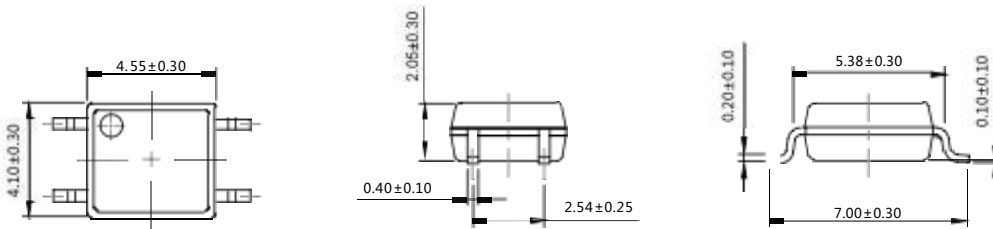
例如，AT304X 系列的电压峰值 $V_{PEAK} = 400V$ 。 dv/dt 值的计算方式如下：

For example, the voltage peak of ATM304X series $V_{PEAK}=400V$. Then the dv/dt value can be calculated as follows :

$$dv/dt = \frac{0.632 \times 400}{\tau_{RC}} = \frac{252}{\tau_{RC}}$$

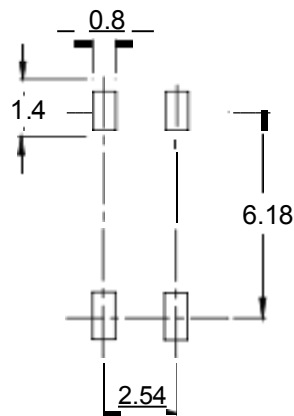
外形尺寸。Outline Dimensions

SOP4



单位 Unit: mm

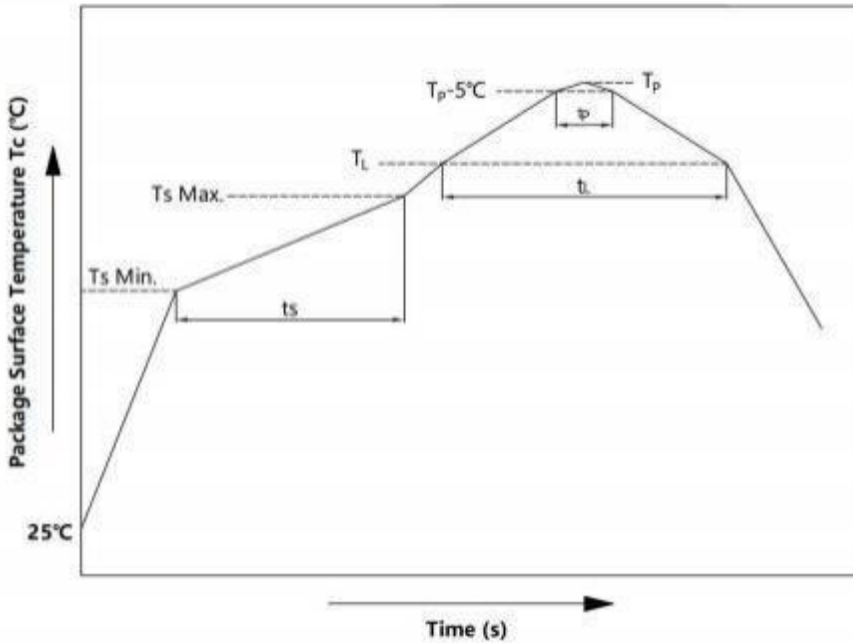
建议焊盘布局 Recommended pad Layout



单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 solderReflowprofile


项目 Item	符号 Symbol	最小值 Min.	最大值 Max	单位 Unit
预热温度 Preheat Temperature	Ts	150	200	°C
预热时间 Preheat Time	ts	60	120	s
升温速率 Ramp-Up Rate (T _L to T _P)	-	-	3	°C/s
液相线温度 Liquidus Temperature	T _L	217		°C
时间高于 T _L Time Above T _L	t _L	60	150	s
峰值温度 Peak Temperature	T _P	-	260	°C
T _c 在(T _P -5)和 T _P 之间的时间 Time During Which T _c Is Between (T _P -5) and T _P	t _p	-	30	s
降温速率 Ramp-down Rate(T _P to T _L)	-	-	6	°C/s

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 wavesoldering profile



手工烙铁焊接 soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。
Hand soldering iron requirements：Temperature： $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s

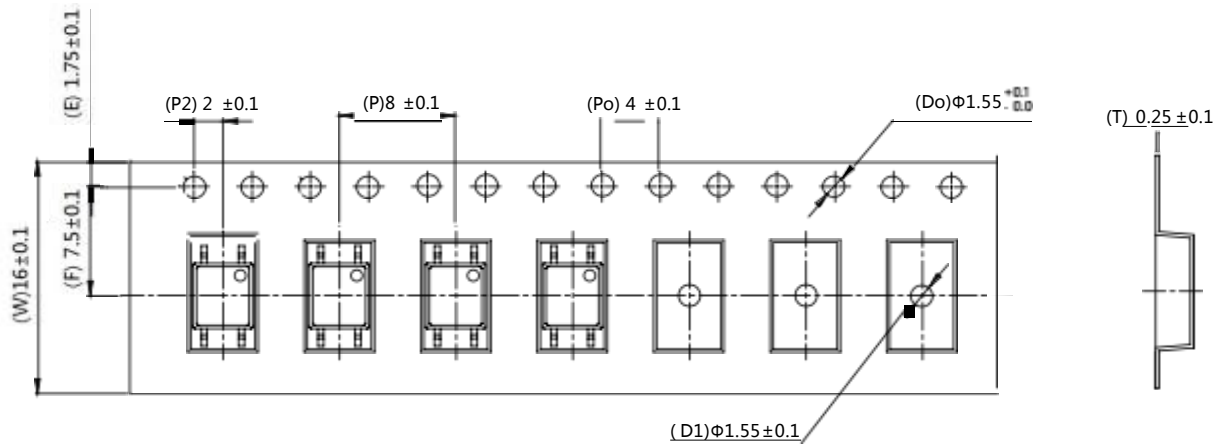
包装 packing

■ 汇总表summarytable

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SOP4	卷盘 ($\phi 330\text{mm}$ 蓝盘)	3000/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	340*60*340mm	380*360*365mm	首尾端空至少 200mm
SOP4	Reel ($\phi 330\text{mm}$ Blue)	3k pcs/reel	2 reels /box	10 boxes /ctn	450*390*0.1mm	340*60*340mm	380*360*365mm	Leave at least 200mm of blank space at both ends

■ 编带包装Tape&Reel

- 1) 每卷数量：3000 只。
Qty/reel：3000 pcs.
- 2) 每箱数量：60000 只。
Qty/ctn：60000 pcs.
- 3) 内包装：每盒 2 盘。
Inner packing：2 reels/box.
- 4) 示意图 Schematic：



单位 Unit：mm

注意 Attention

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